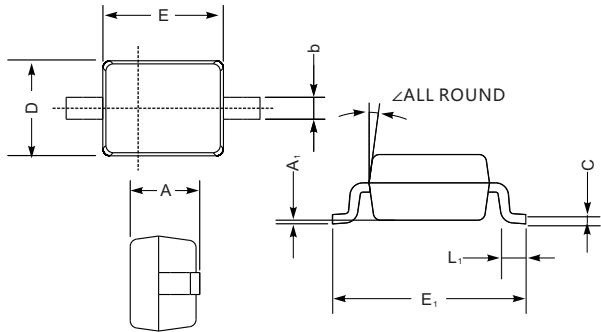


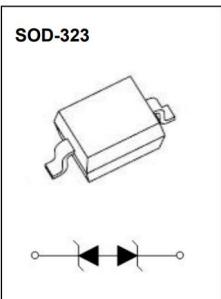
Features

- Bi-directional ESD protection of one line
- Reverse stand-off voltage: 12V
- Low reverse clamping voltage
- Low leakage current
- Fast response time
- IEC 61000-4-2 (ESD) immunity test :
- Air discharge: $\pm 30kV$
- Contact discharge: $\pm 30kV$



Marking Diagram

12C



SOD-323 mechanical data

UNIT		A	C	D	E	E ₁	b	L ₁	A ₁	∠
mm	max	1.1	0.15	1.4	1.8	2.75	0.4	0.45	0.2	9°
	min	0.8	0.08	1.2	1.4	2.55	0.25	0.2	—	
mil	max	43	5.9	55	70	108	16	16	8	9°
	min	32	3.1	47	63	100	9.8	7.9	—	

Description

Designed to protect voltage sensitive electronic components from ESD and other transients. Excellent clamping capability, low leakage, low capacitance, and fast response time provide best in class protection on designs that are exposed to ESD.

The combination of small size, low capacitance, and high level of ESD protection makes them a flexible solution for applications such as HDMI, Display Port TM, and MDDI interfaces. It is designed to replace multiplayer varistors (MLV) in consumer equipments applications such as mobile phone, notebook, PAD, STB, LCD TV etc.

Applications

- Computers and peripherals
- High speed data lines
- Audio and video equipment
- Cellular handsets and accessories
- Subscriber identity module(SIM) card protection
- Portable electronics
- FireWire
- Other electronics equipments communication systems

ES12D1HA03

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

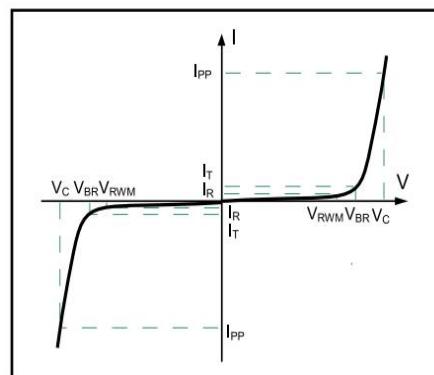
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	450	W
Peak Pulse Current (8/20μs)	IPP	15	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	VRWM				12	V
Breakdown Voltage	VBR	$I_T = 1\text{mA}$	14.2		16.2	V
Reverse Leakage Current	IR	$VRWM = \pm 12\text{V}$			0.1	uA
Clamping Voltage	Vc	$I_{PP} = 15\text{A}$ (8 x 20μs pulse)			28	V
Junction Capacitance	Cj	$VR = 0\text{V}$, $f = 1\text{MHz}$			45	pF

Electronics Parameter

Symbol	Parameter
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_T
V_{BR}	Breakdown Voltage @ I_T
I_R	Reverse Leakage Current @ $VRWM$
V_{RWM}	Reverse Standoff Voltage



Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)

